NSN 5962-01-468-4934

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Maximum Power Dissipation Rating:
1.0 watts
Operating Tempurature Range:
-55.0/+125.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
End Application:
V) 3 unit 7-8/avenger class mcm
Features Provided:
Monolithic and electrostatic sensitive
Inclosure Material:
Ceramic
Inclosure Configuration:
Leaded chip carrier
Product Name:
Microcircuit, memory, digital, cmos 128 x 8 bit eeprom, monolithic silicon
Voltage Rating And Type Per Characteristic:
-0.5 volts input and 6.0 volts input
Memory Device Type:
Eeprom
Special Features:
Accesstime-150ns, write speed-10ns, write mode-byte/page, endurance-10, 000 cycle, software data protection-yes
Test Data Document:
96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).
Terminal Type And Quantity:
32 printed circuit
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
Yes - demil/mli
Fiig:
A458a0